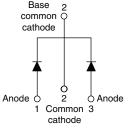
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VS-10CTQ150PbF, VS-10CTQ150-N3

Vishay Semiconductors

TO-220AB



Base

PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 5 A			
V _R	150 V			
V _F at I _F	0.73 V			
I _{RM} max.	7 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Common cathode			
E _{AS}	6.75 mJ			

FEATURES

Schottky Rectifier, 2 x 5 A

- 175 °C T_J operation
- · Center tap configuration
- Low forward voltage drop
- High frequency operation
- epoxy RoHS • High purity, high temperature COMPLIANT encapsulation for enhanced mechanical strength HALOGEN and moisture resistance FREE



- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	10	А		
V _{RRM}		150	V		
I _{FSM}	t _p = 5 μs sine	620	А		
V _F	$5 \text{ A}_{\text{pk}}, \text{ T}_{\text{J}} = 125 \text{ °C} \text{ (per leg)}$	0.73	V		
TJ	Range	- 55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-10CTQ150PbF	VS-10CTQ150-N3	UNITS	
Maximum DC reverse voltage	V _R	150	150	V	
Maximum working peak reverse voltage	V _{RWM}	150	150	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg	l=(1) A	50 % duty cycle at T_{C} = 155 °C, rectangular waveform –		5	А
See fig. 5 per device	I _{F(AV)}			10	~
Maximum peak one cycle non-repetitive surge current per leg	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated 10 ms sine or 6 ms rect. pulse V _{RRM} applied	620	А		
See fig. 7		10 ms sine or 6 ms rect. pulse		115	
Non-repetitive avalanche energy per leg		T _J = 25 °C, I _{AS} = 0.30 A, L = 150 mH		6.75	mJ
Repetitive avalanche current per leg		Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		0.30	А

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1



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ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg		5 A	T 05 %C	0.93	V
	V _{FM} ⁽¹⁾	10 A	T _J = 25 °C	1.10	
See fig. 1	VFM ("	5 A	T = 105 °C	0.73	
		10 A	− T _J = 125 °C	0.86	
Maximum reverse leakage current per leg See fig. 2	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.05	mA
		T _J = 125 °C		7	
Threshold voltage	V _{F(TO)}	$T_J = T_J maximum$		0.468	V
Forward slope resistance	r _t			28	mΩ
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		200	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC} DC c	DC operation	3.50	°C/W
Maximum thermal resistance, junction to case per package				1.75	
Typical thermal resistance, case to heatsink (only for TO-220)		R _{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220AB		Q150



VS-10CTQ150PbF, VS-10CTQ150-N3

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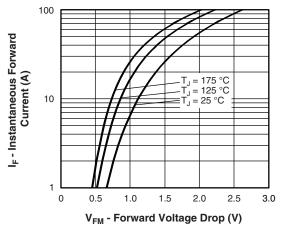
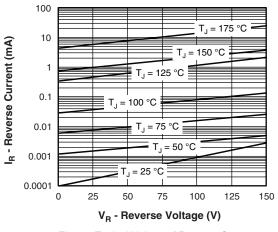
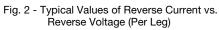


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





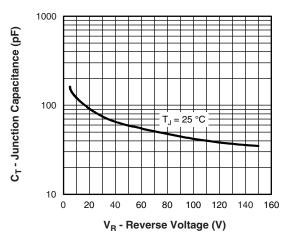
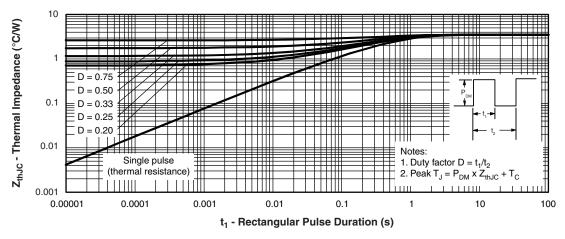
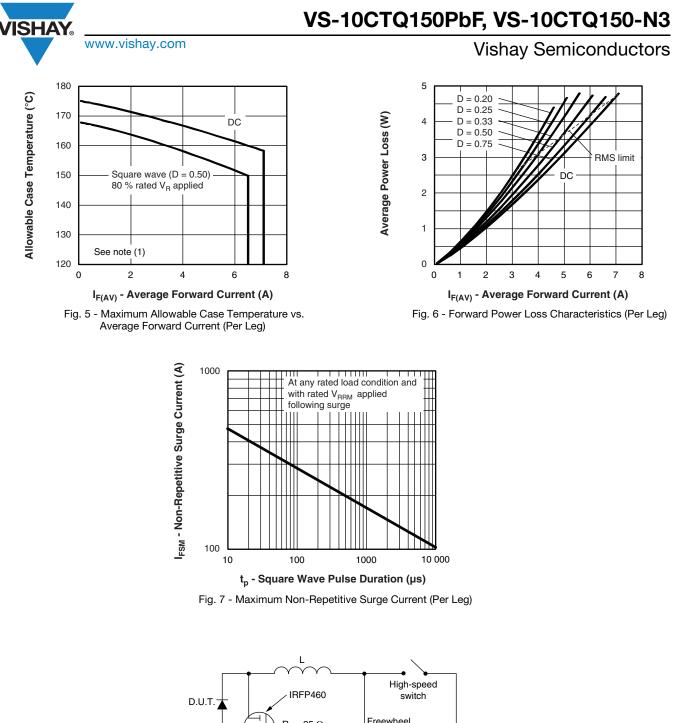


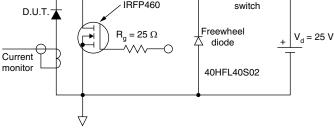
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

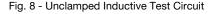




Revision: 22-Aug-11	3	Document Number: 94115
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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{10} \ \mathsf{V} \end{array}$

Revision: 22-Aug-11

4

Document Number: 94115

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VS-10CTQ150PbF, VS-10CTQ150-N3



Vishay Semiconductors

ORDERING INFORMATION TABLE

 Vishay Semiconductors product Current rating (10 = 10 A) Circuit configuration C = Common cathode
4 - Package T = TO-220
 5 - Schottky "Q" series 6 - Voltage rating (150 = 150 V) 7 - Environmental digit
 PbF = Lead (Pb)-free and RoHS compliant, a -N3 = Halogen-free, RoHS compliant, a

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-10CTQ150PbF	50	1000	Antistatic plastic tube		
VS-10CTQ150-N3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95222				
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028		

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